



BAS70/ -04/ -05/ -06

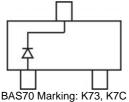
SURFACE MOUNT SCHOTTKY BARRIER DIODE

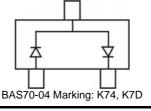
Features

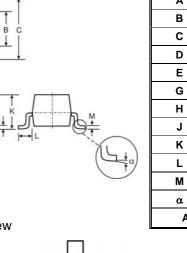
- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- Lead Free/RoHS Compliant (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Polarity: See Diagrams Below
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)

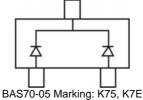


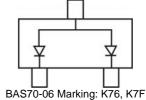




SOT-23								
Dim	Min	Max						
Α	0.37	0.51						
В	1.20	1.40 2.50						
С	2.30							
D	0.89	1.03						
Е	0.45	0.60						
G	1.78	2.05						
н	2.80	3.00						
J	0.013	0.10						
к	0.903	1.10						
L	0.45	0.61						
М	0.085	0.180						
α	0°	8°						
All Dimensions in mm								

Top View





Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage	V _{RRM}			
Working Peak Reverse Voltage	V _{RWM}	70	V	
DC Blocking Voltage	V _R			
RMS Reverse Voltage	V _{R(RMS)}	49	V	
Maximum Forward Continuous Current (Note 1)	I _{FM}	70	mA	
Non-Repetitive Peak Forward Surge Current $@ t \le 1.0s$	I _{FSM}	100	mA	
Power Dissipation (Note 1)	Pd	200	mW	
Thermal Resistance Junction to Ambient Air (Note 1)	$R_{ ext{ heta}JA}$	625	°C/W	
Operating Junction Temperature Range	Тj	-55 to +125	°C	
Storage Temperature Range	T _{STG}	-65 to +150	°C	

Electrical Characteristics @T_A = 25°C unless otherwise specified

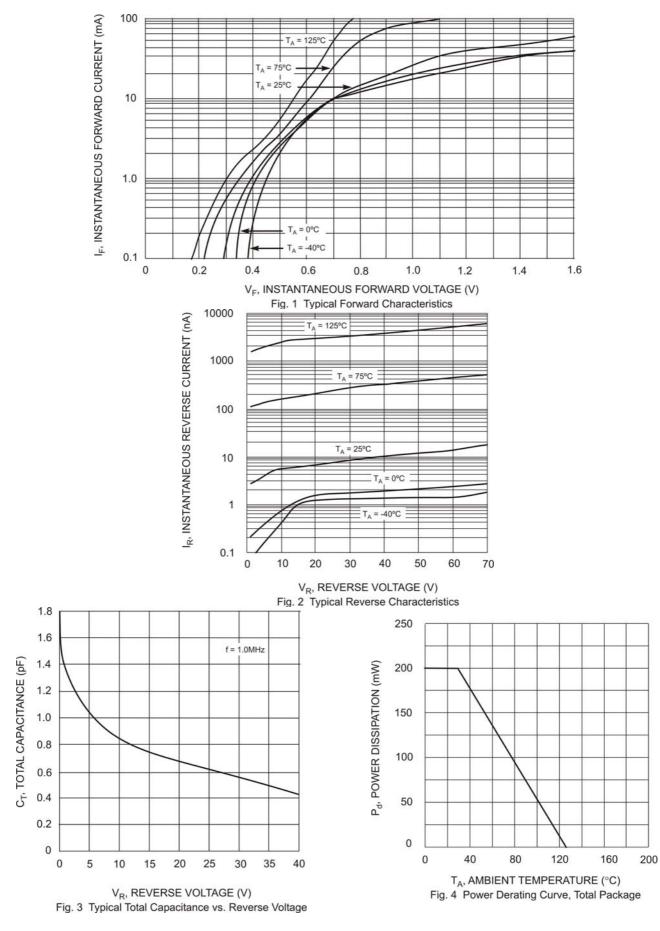
Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	V _{(BR)R}	70	_	V	$I_R = 10 \mu A$
Forward Voltage	V _F	—	410 1000	mV	t _p <300µs, I _F = 1.0mA t _p <300µs, I _F = 15mA
Reverse Current (Note 2)	I _R	_	100	nA	t _p <300µs, V _R = 50V
Total Capacitance	CT	_	2.0	pF	$V_{R} = 0V, f = 1.0MHz$
Reverse Recovery Time	t _{rr}		5.0	ns	$I_F = I_R = 10$ mA to $I_R = 1.0$ mA, $R_L = 100\Omega$

Notes:

Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
Short duration pulse test used to minimize self-heating effect.

3. No purposefully added lead.





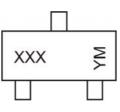


Ordering Information (Note 4)

Device	Packaging	Shipping		
BAS70-7-F	SOT-23	3000/Tape & Reel		
BAS70-04-7-F	SOT-23	3000/Tape & Reel		
BAS70-05-7-F	SOT-23	3000/Tape & Reel		
BAS70-06-7-F	SOT-23	3000/Tape & Reel		

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code (See Page 1) YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2001	2002	2003	2004	2005	2006	200	7 20	008 2	2009	2010	2011	2012
Code	М	Ν	Р	R	S	Т	U		V	W	Х	Y	Z
Ν	Ionth	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
(Code	1	2	3	4	5	6	7	8	9	0	Ν	D

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